

Cu(In,Ga)Se₂ thin-film micro-concentrator solar cells

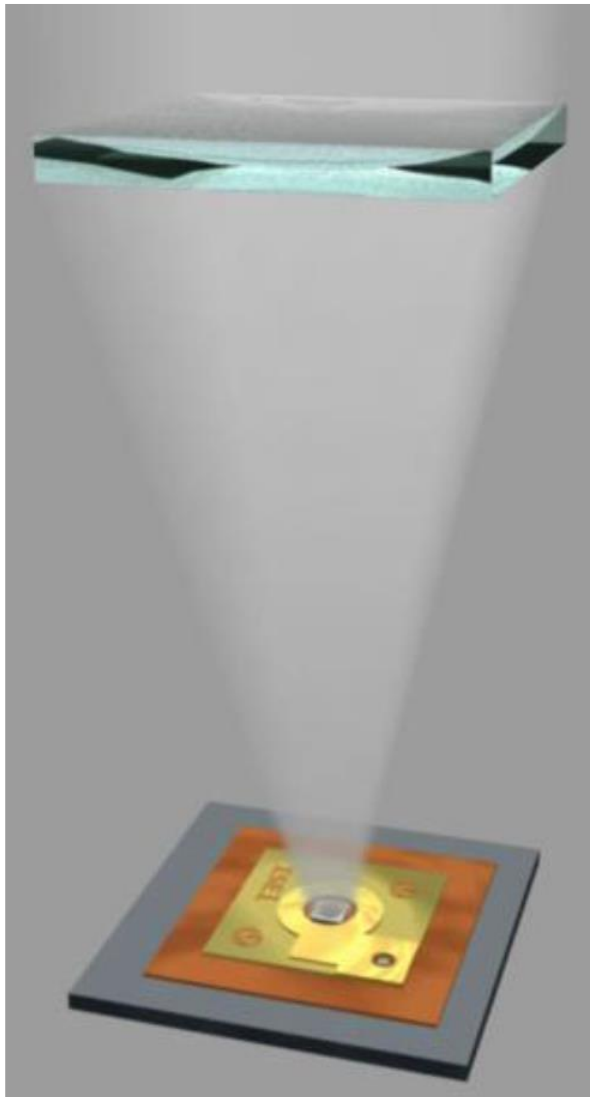
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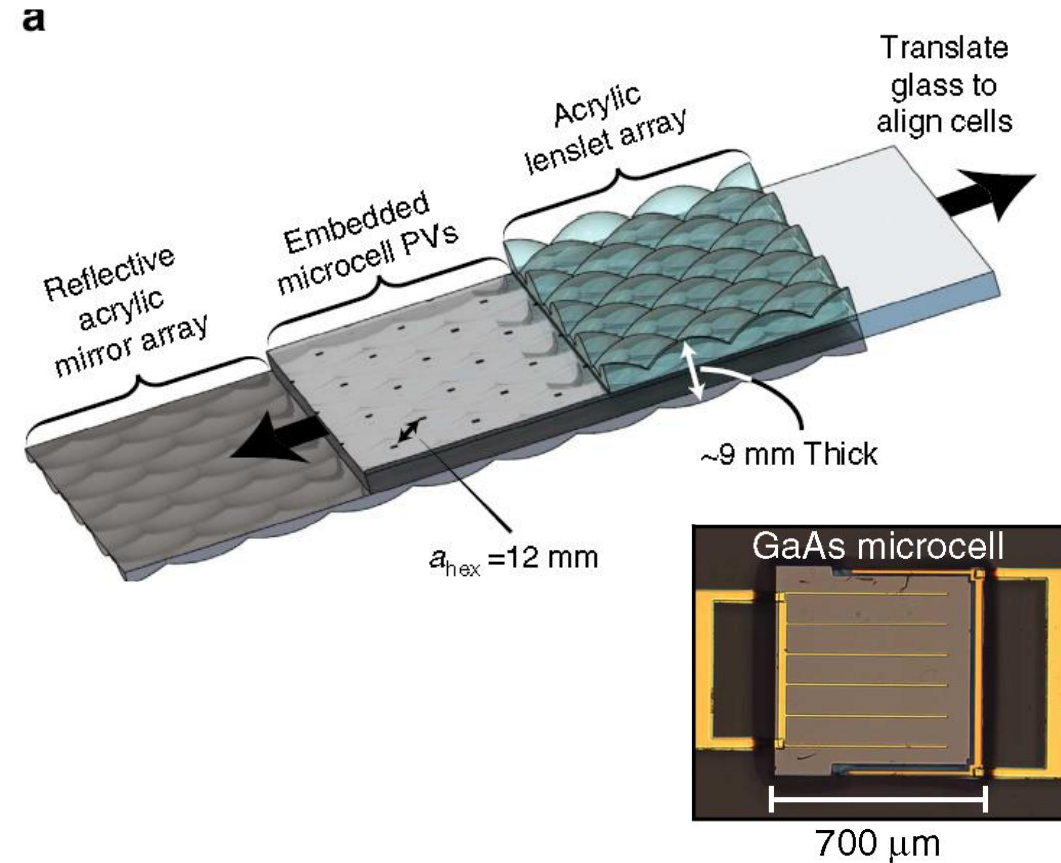
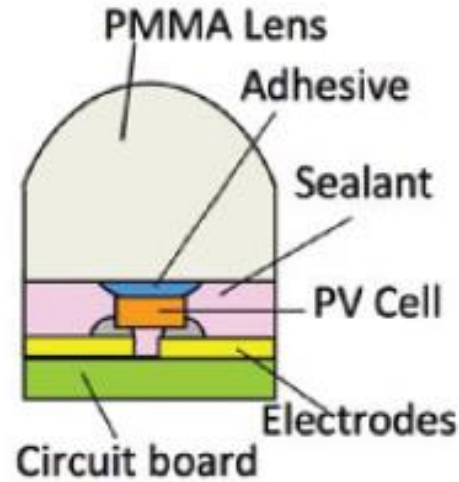
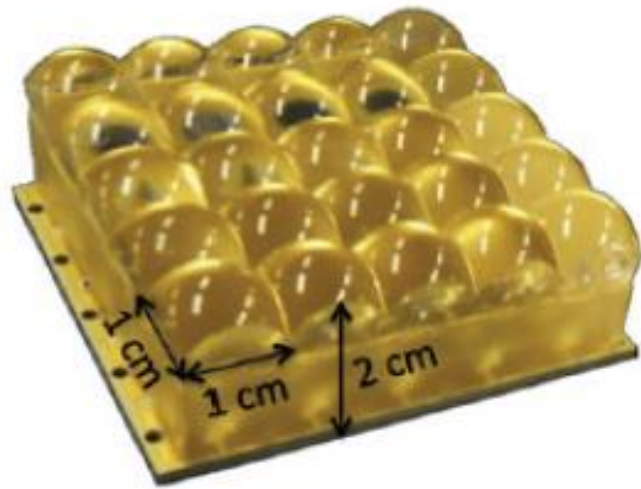
³ Instituto de Energía Solar, Universidad Politécnica de Madrid, 28040 Madrid, Spain

⁴ ETS de Ingeniería y Diseño Industrial, Universidad Politécnica de Madrid. 28012 Madrid, Spain



- Idea: Reduce area of solar cell and replace by more cost-efficient optics
- Solar cell area $\sim 1 \text{ cm}^2$
- Mostly employs III-V multi-junction solar cells
- Bulky modules
- Sun tracking required \rightarrow bulky tracker
- Cooling required

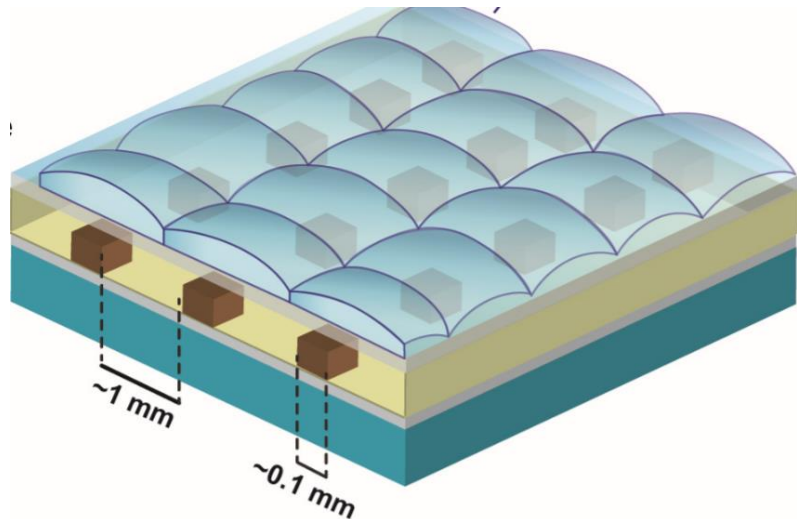
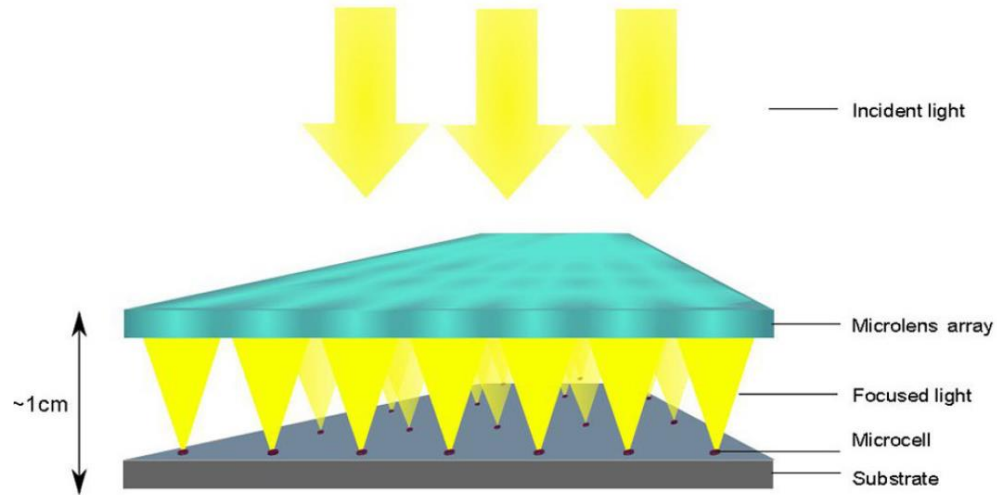
M. Wiesenfarth et al., CPV Report TP-6A20-63916 Natl. Renew. Energy Lab (2017).



- Idea: Reduce area of solar cell further
- Solar cell area sub- mm^2
- Mostly employs III-V multi-junction solar cells
- Modules get slimmer
- Sun tracking required \rightarrow option for integrated tracking
- Cooling required

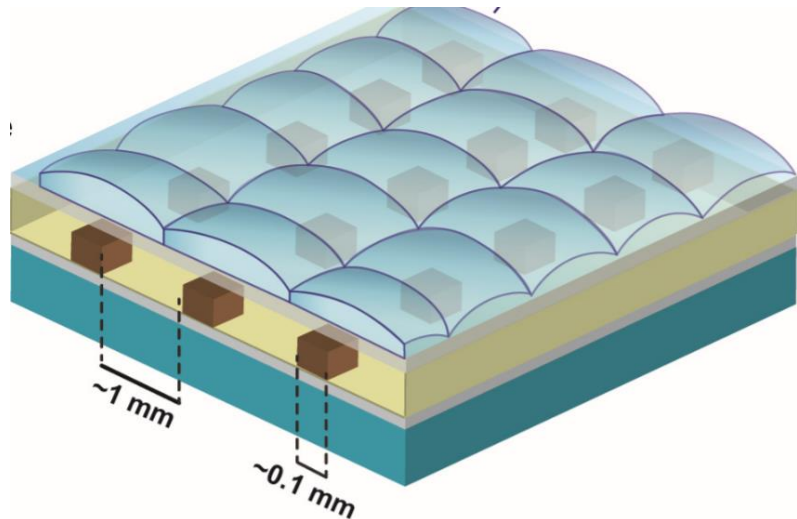
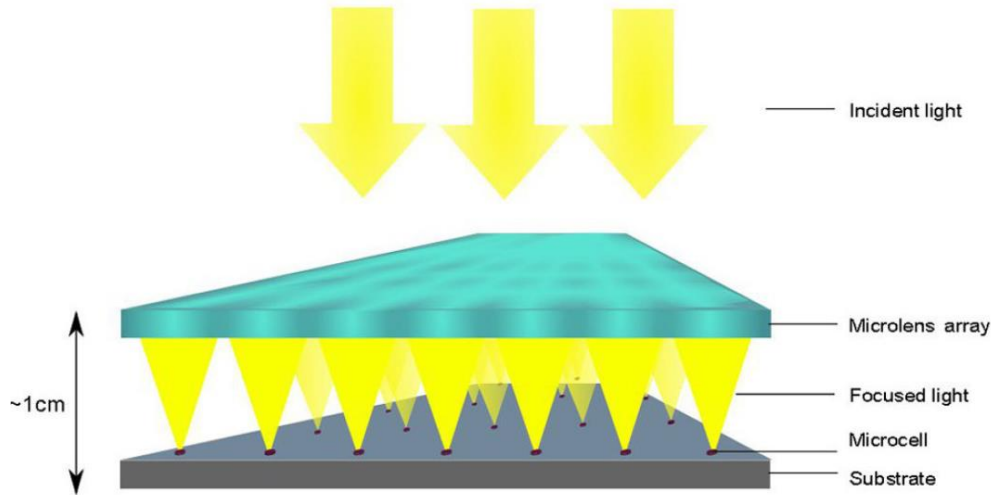
O. Fidaner et al., Appl. Phys. Lett. 104, 103902 (2014).
 J.S. Price et al., Nature Comm. 6, 6223 (2015).

The Concept



M. Paire et al., SPIE Newsroom 5, 2 (2013)
M. Alves et al., J. Phys.: Energy 2, 012001 (2020).

The Concept



Why ?

- Decrease significantly the use of critical raw materials (In, Ga)
- Decrease solar cell size to $\sim 100 \mu\text{m}$
- Increase efficiency
- Heat input per cell is reduced. As the ratio of surface area to volume becomes higher, heat dissipation is improved.
- Cu(In,Ga)Se₂ enables direct structured deposition
- Shorter optical paths lead to lower absorption losses.
- The short focal length leads to thin modules that employ less material.
- The current generated at each cell is lower → series resistance losses can be reduced.
- Lower impact of light spot inhomogeneity

M. Paire et al., SPIE Newsroom 5, 2 (2013)
 M. Alves et al., J. Phys.: Energy 2, 012001 (2020).

→ Significant decrease in use of critical raw materials (In, Ga)

→ Increase efficiency

→ Improved heat dissipation at micrometer scale

Rough Estimates:

Regular CIGSe thin-film photovoltaics:

- Indium per m^2 : ~ 2 g
- If all PV production of 1 year would be CIGSe: 100 GW
- 1 module with 20% efficiency gives 200 W/ m^2
- → 500×10^6 m^2 CIGSe production / year
- → 1000 tons indium / year
- Annual In production in 2019: 760 tons

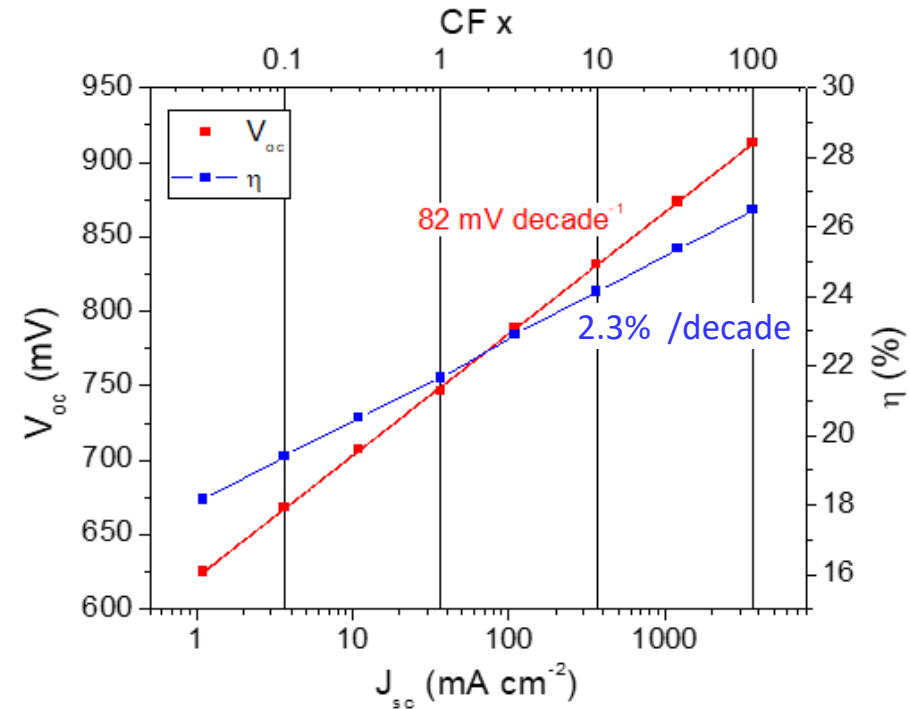
For micro-concentrator with 100X concentration:

- → Indium need of 10 tons / year

- Significant decrease in use of critical raw materials (In, Ga)
- **Increase efficiency**
- Improved heat dissipation at micrometer scale

- Concentrated light leads to an increase in V_{oc}

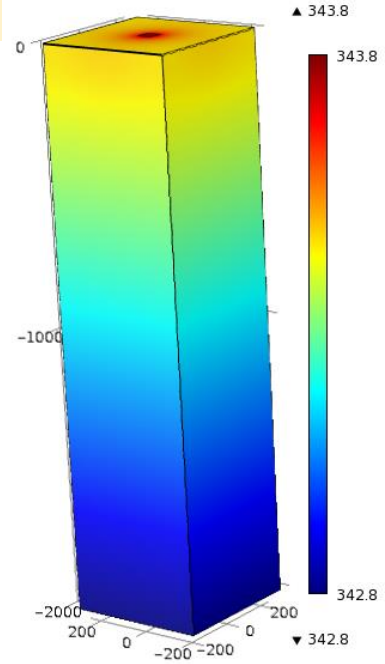
$$V_{oc} = \frac{Ak_B T}{q} \ln\left(\frac{J_{ph}}{J_0} + 1\right)$$



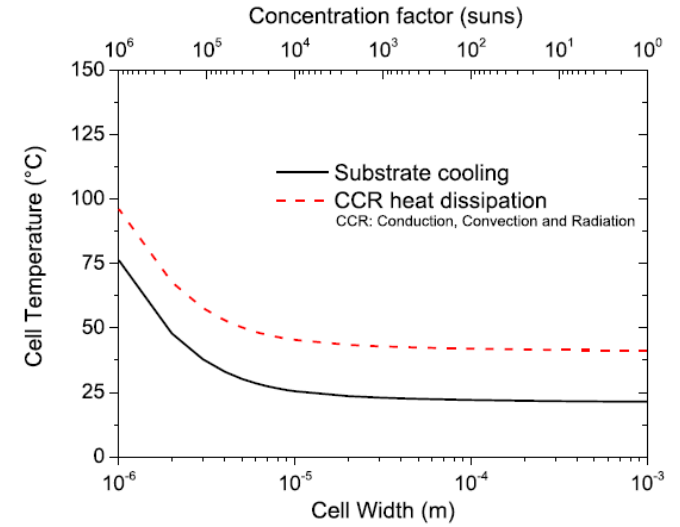
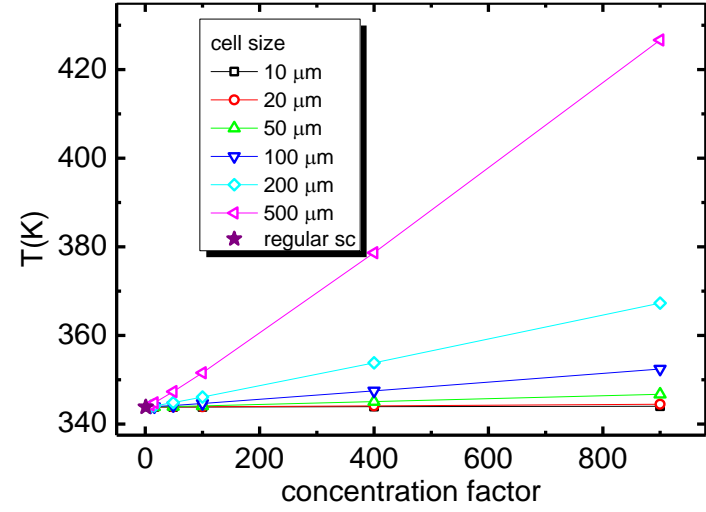
D. Siopa et al., submitted (2020)
 P. Jackson et al., *pss RRL* 9, 28 (2015).

- Parameters from P. Jackson 21.7% solar cell
- Assume no change in FF, A, J_0 with concentration

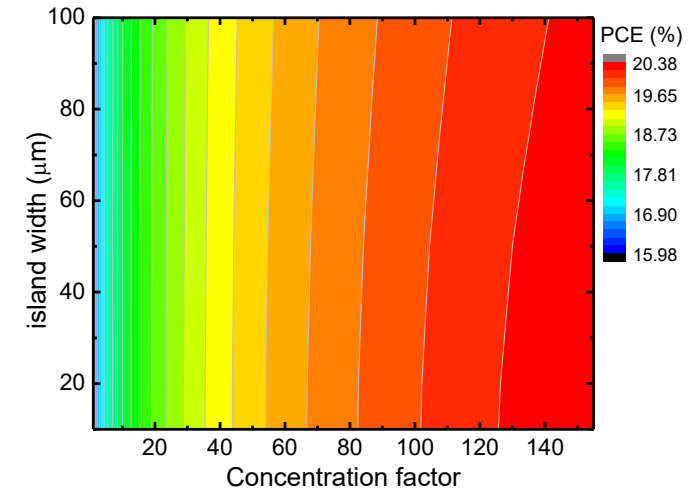
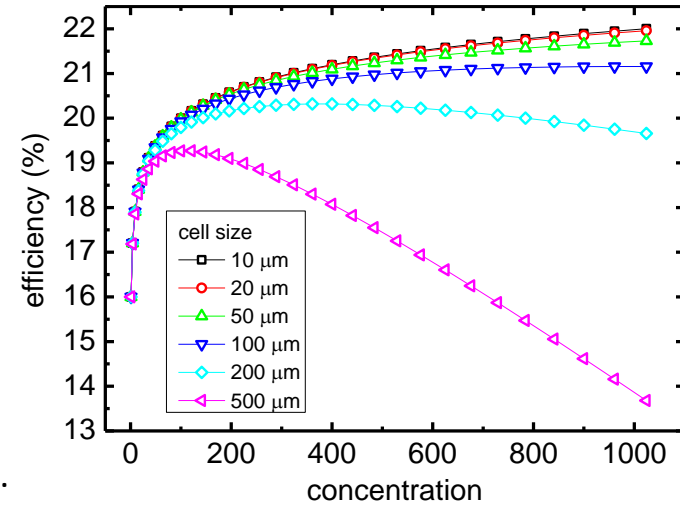
- Significant decrease in use of critical raw materials (In, Ga)
- Increase efficiency
- **Improved heat dissipation at micrometer scale**



- Heat management through finite element simulations

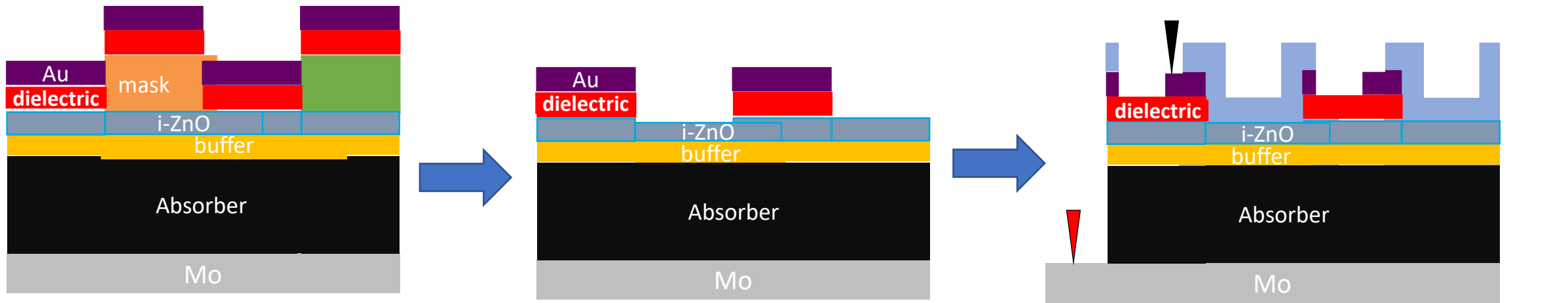


- Efficiency → positive effect of V_{oc} & negative effect of temperature



S. Sadewasser et al., *Sol. Energy Mat. Sol. Cells* 159, 496 (2017).
 S. Sadewasser, *Solar Energy* 158, 186 (2017).
 D. Sancho-Martínez et al., *J. Phys. D: Appl. Phys.* 50, 445501 (2017).

- Insulating top contact by dielectric layer and shadowing by metallic layer



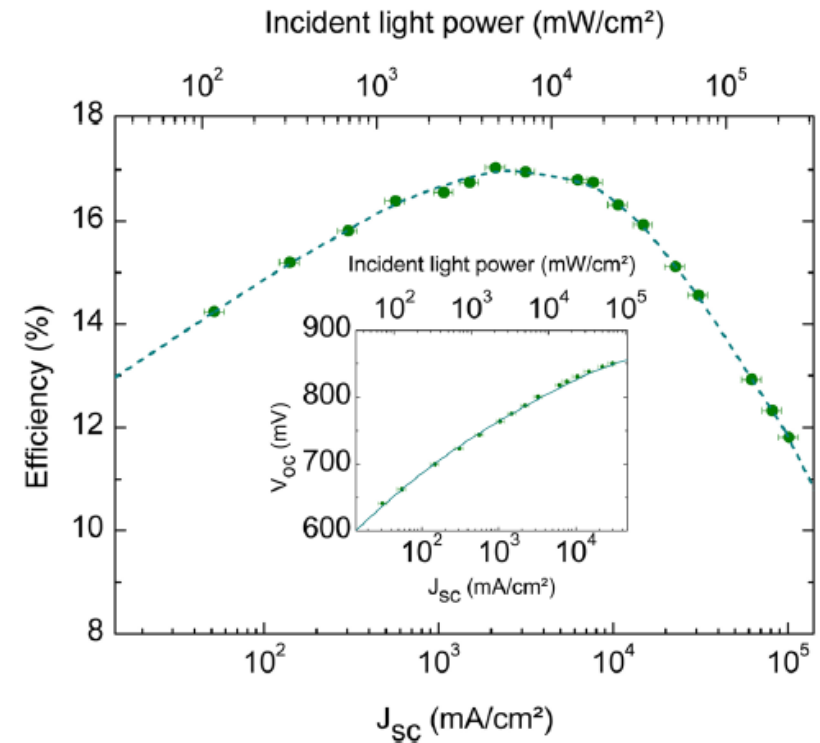
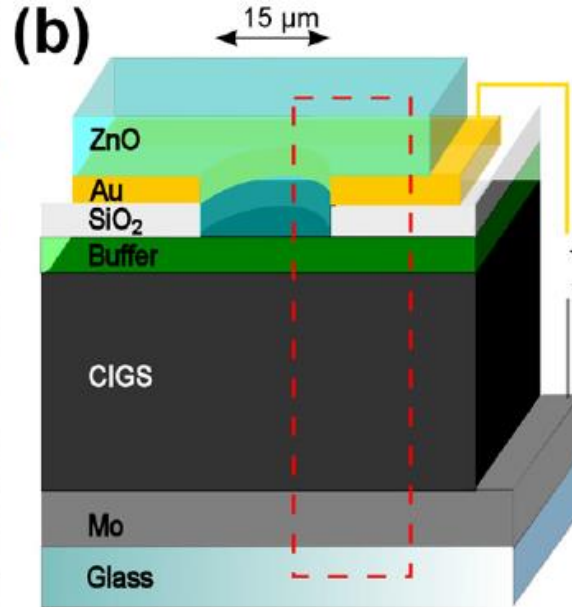
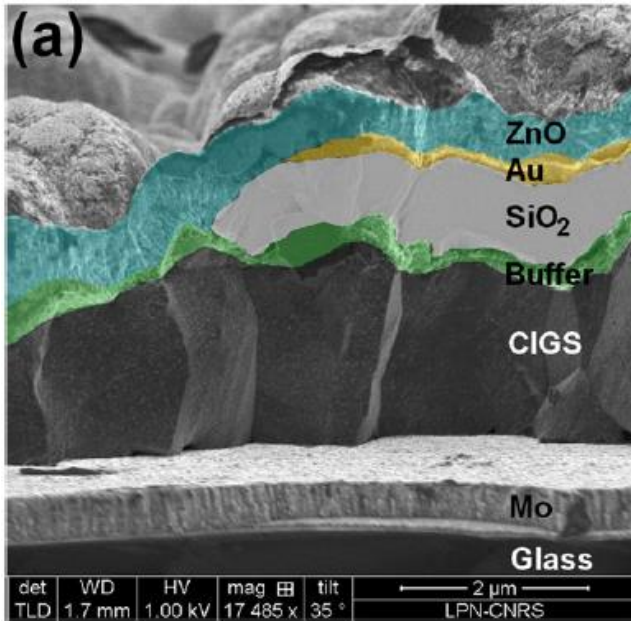
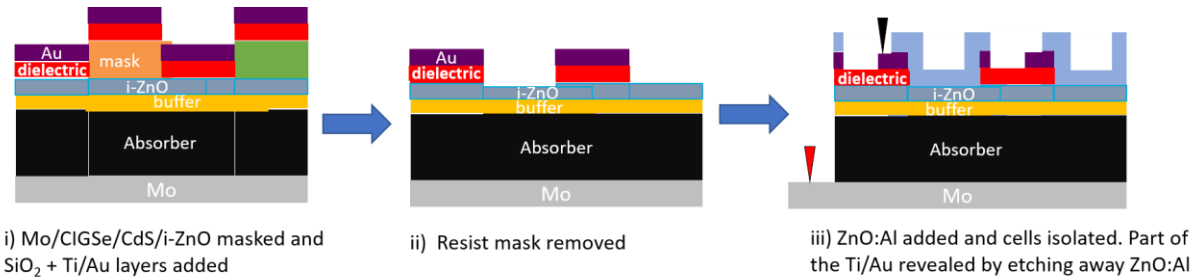
i) Mo/CIGSe/CdS/i-ZnO masked and SiO₂ + Ti/Au layers added

ii) Resist mask removed

iii) ZnO:Al added and cells isolated. Part of the Ti/Au revealed by etching away ZnO:Al

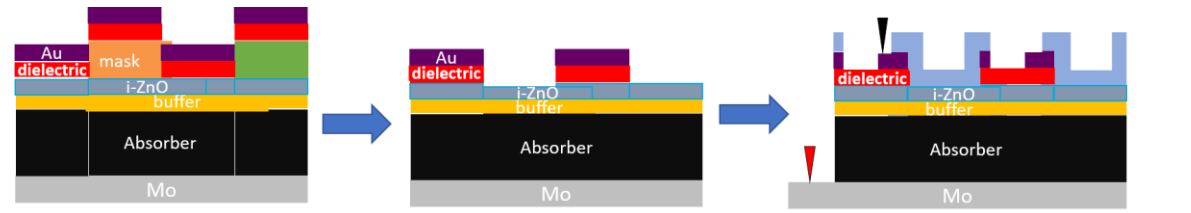
M. Paire et al., Appl. Phys. Lett. 98, 264102 (2011).

- Insulating top contact by dielectric layer and shadowing by metallic layer



- $\eta=17\%$ @ 120X concentration
- Logarithmic V_{oc} increase up to 1000X conc.
- Series resistance from electrical contacts and the absorber layer lead to decrease for higher conc.

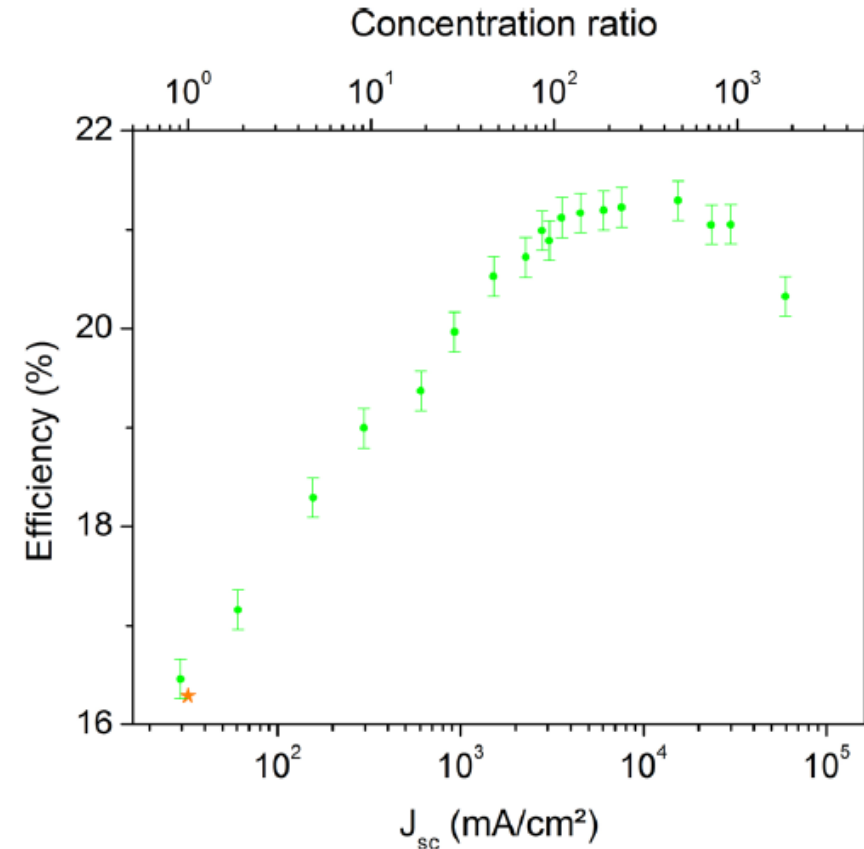
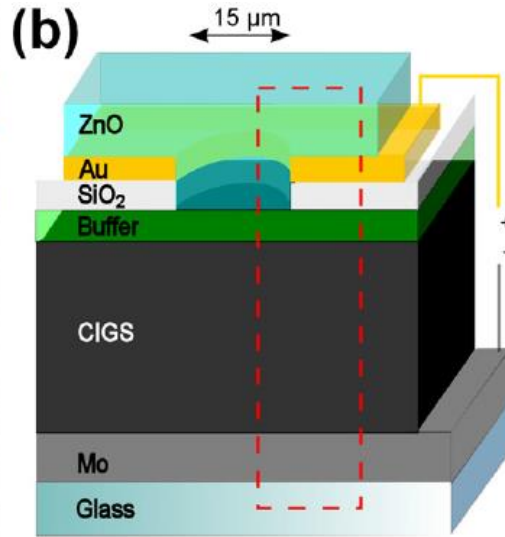
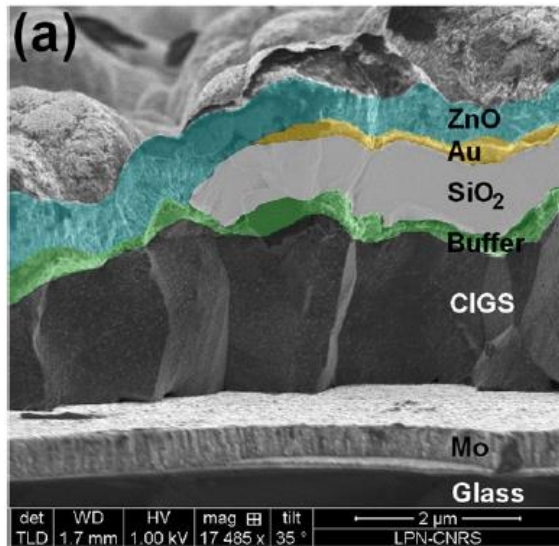
- Insulating top contact by dielectric layer and shadowing by metallic layer



i) Mo/CIGSe/CdS/i-ZnO masked and $\text{SiO}_2 + \text{Ti/Au}$ layers added

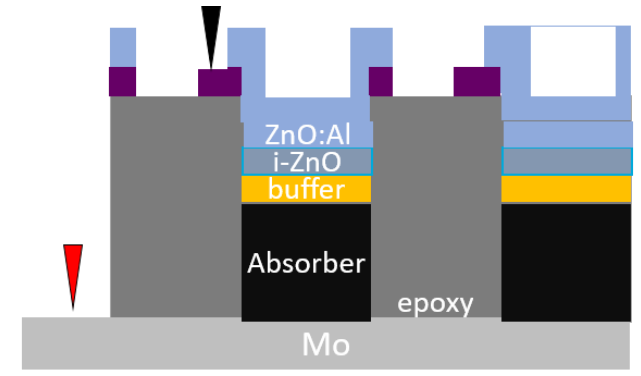
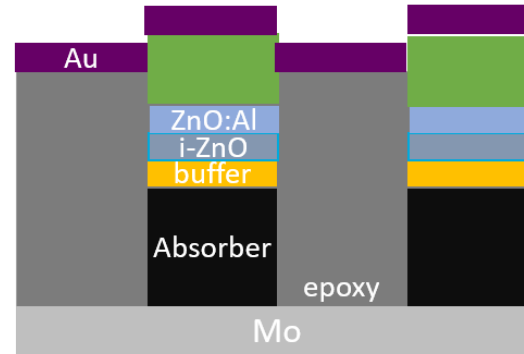
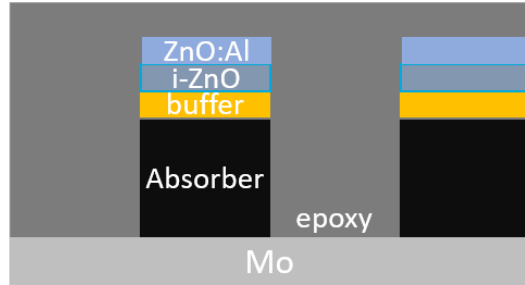
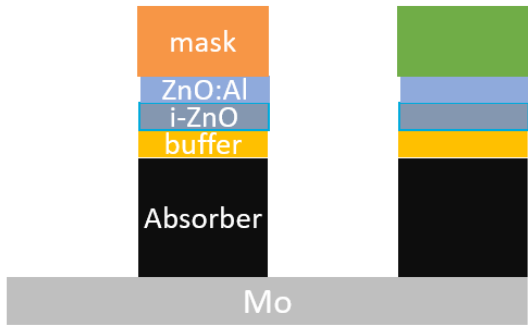
ii) Resist mask removed

iii) ZnO:Al added and cells isolated. Part of the Ti/Au revealed by etching away ZnO:Al



- $\eta = 21.3\%$ @ 475X concentration for 50 μm micro solar cell

- Etch top contacts and absorber using photolithography defined mask and protect with epoxy from shunting



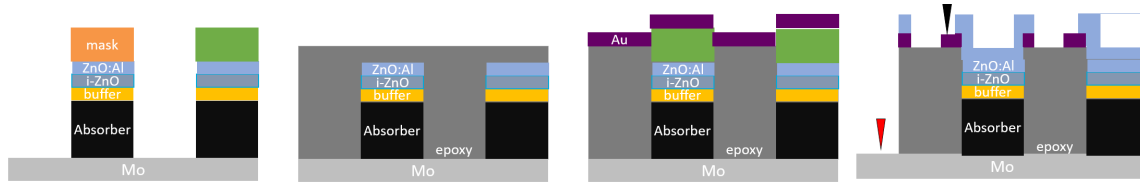
i) Mo/CIGSe/CdS/i-ZnO/
ZnO:Al masked and
etched twice

ii) Resist mask removed
and epoxy resin layer
added

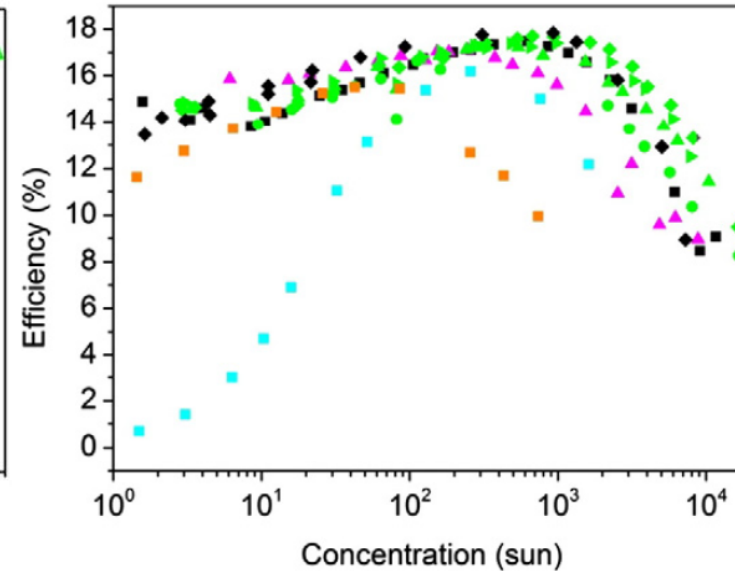
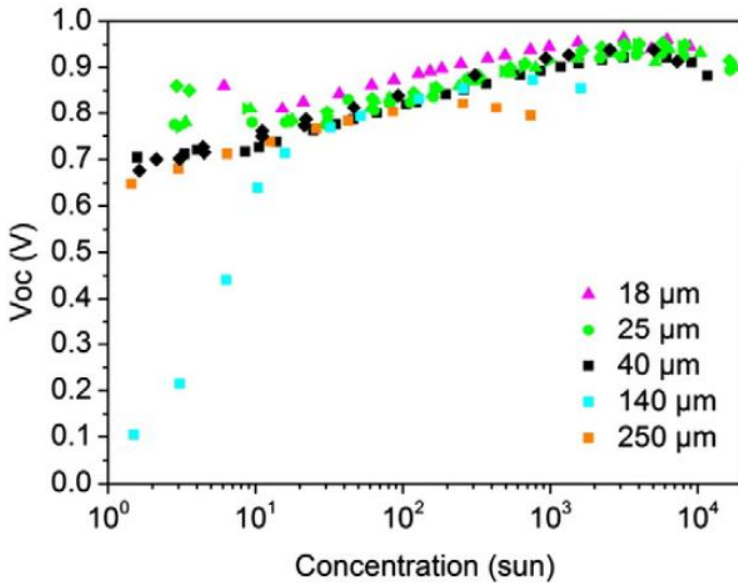
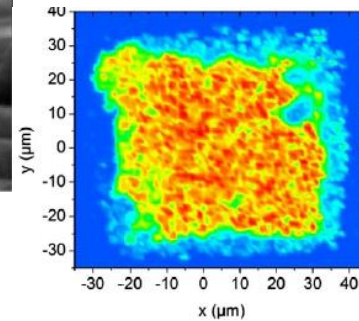
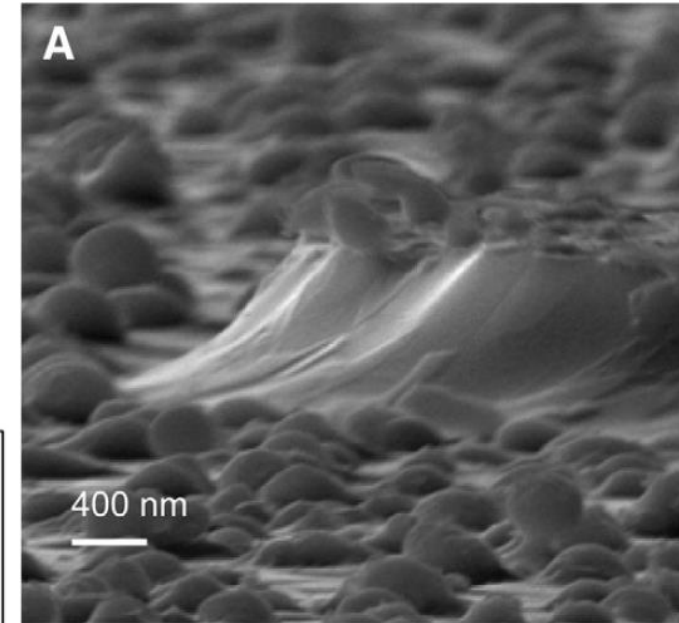
iii) Micro cells revealed
and protected by mask
with Ti/Au contact
layer added

iv) ZnO:Al added and cells
isolated. Part of the Ti/Au
revealed by etching away
ZnO:Al

- Etch top contacts and absorber using photolithography defined mask and protect with epoxy from shunting

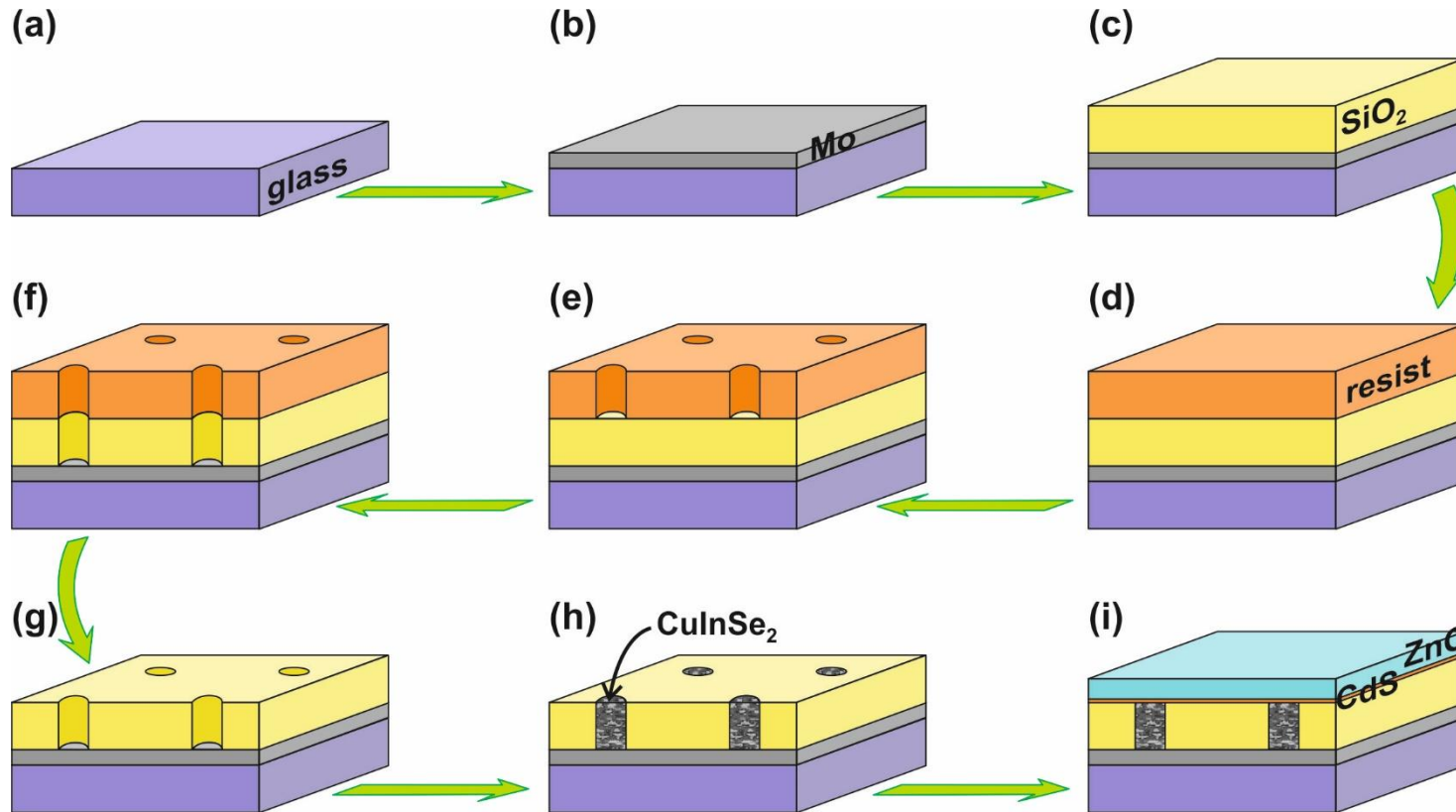


- Mo/CIGSe/CdS/i-ZnO/ZnO:Al masked and etched twice
- Resist mask removed and epoxy resin layer added
- Micro cells revealed and protected by mask with Ti/Au contact layer added
- ZnO:Al added and cells isolated. Part of the Ti/Au revealed by etching away ZnO:Al



- $\eta=18\%$ @ 900X concentration (40μm cell)
- Well passivated edges confirmed by LBIC and PL measurements

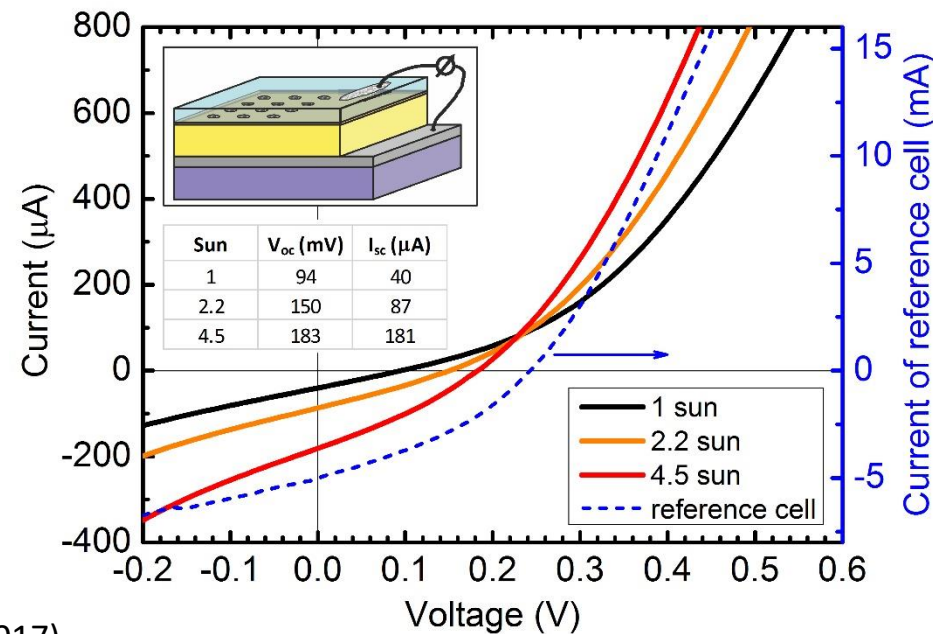
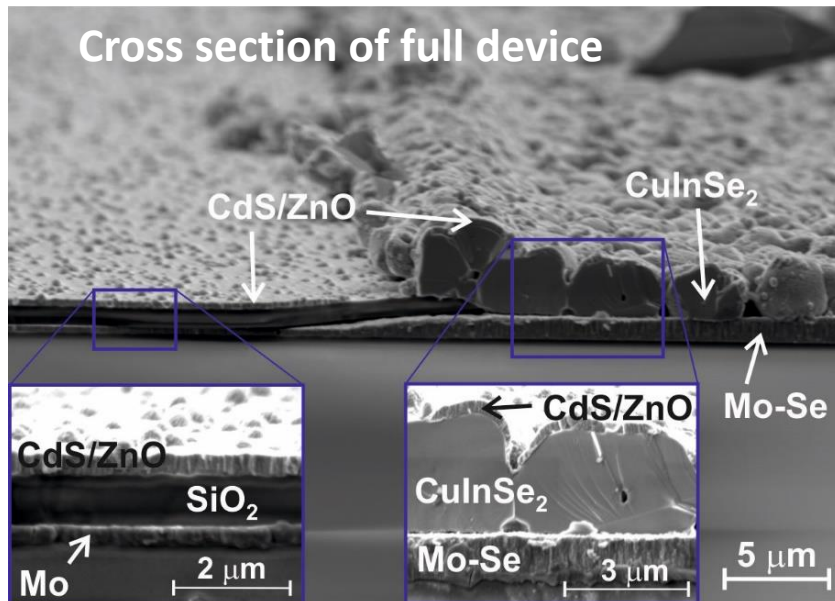
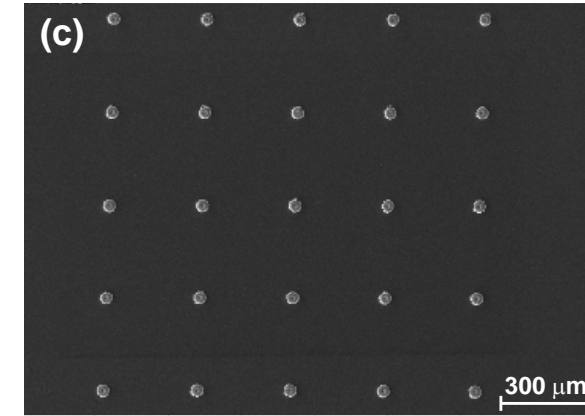
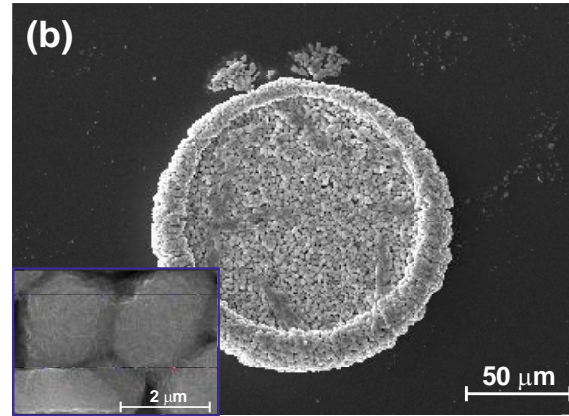
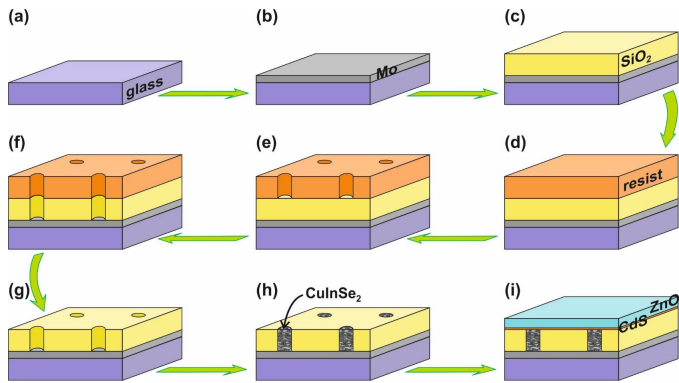
- CIGSe by electrodeposition on micro-electrodes



Fabrication:

- Photolithography and reactive ion etching for etching holes into a SiO₂ layer on Mo back contact
- Electrodeposition of CuInSe₂ into holes and selenization
- Finish solar cell device by regular CdS and ZnO deposition

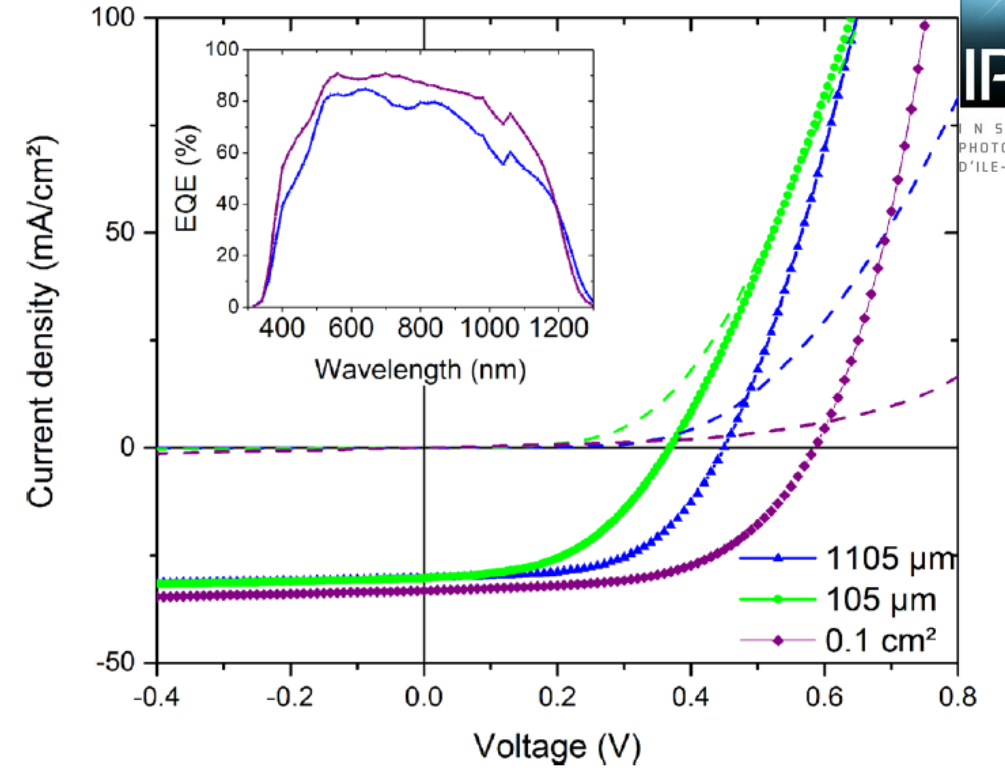
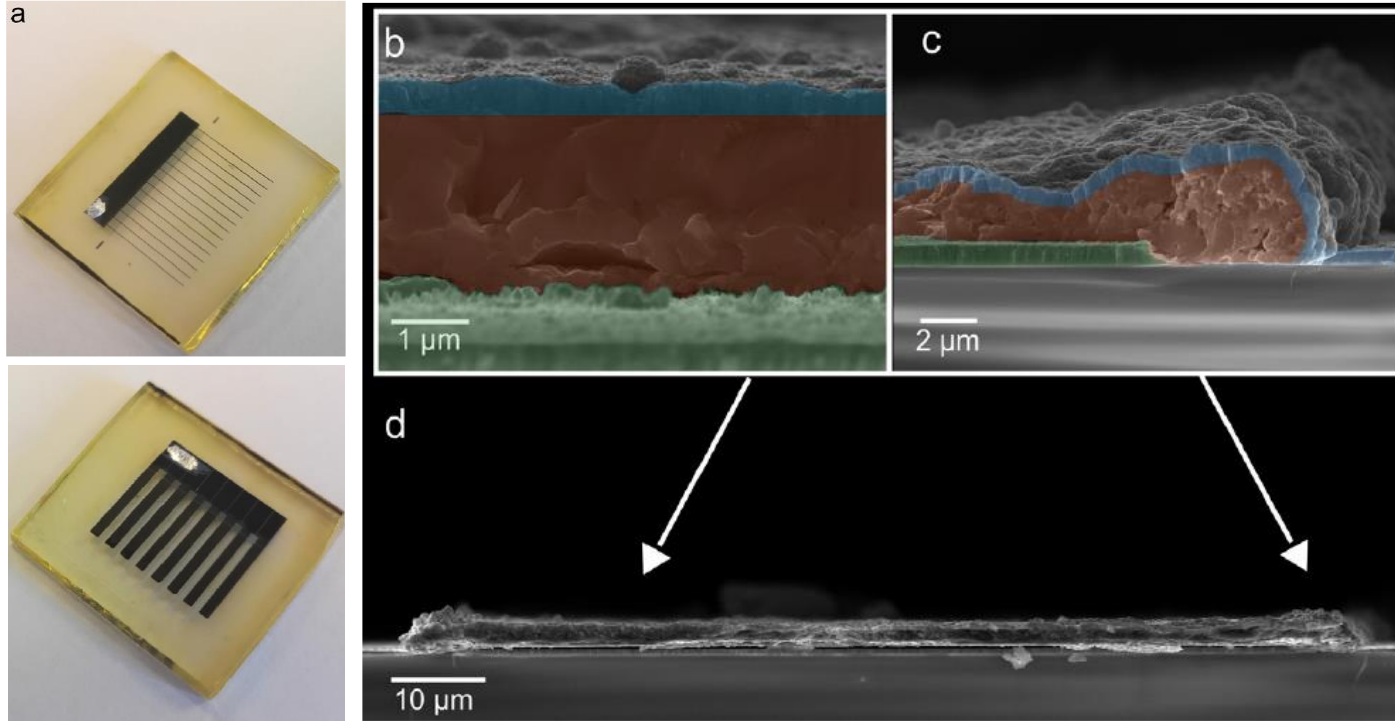
- CIGSe by electrodeposition on micro-electrodes



- V_{oc} increase with concentration
- Poor cell performance

S. Sadewasser et al., Sol. Energy Mater. Sol. Cells 159, 496 (2017).

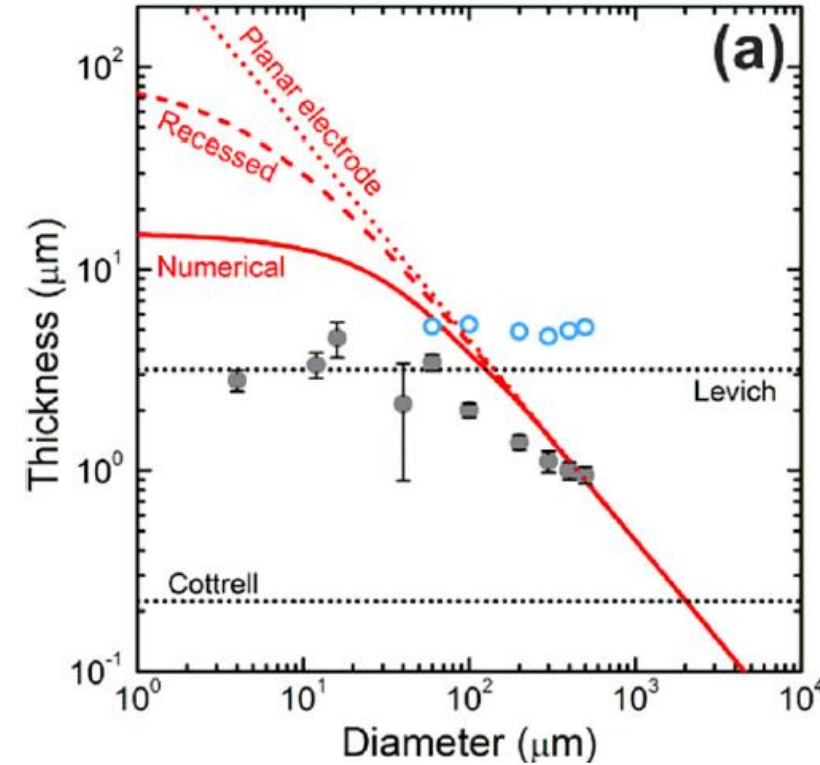
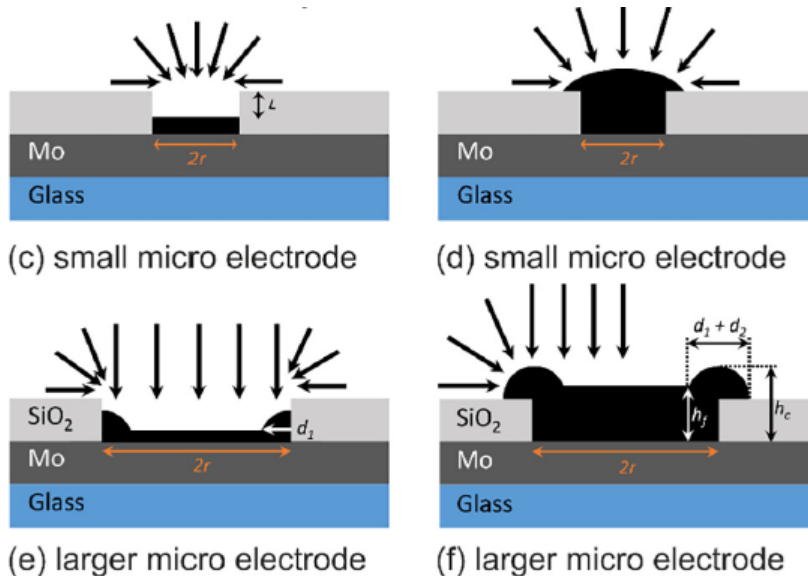
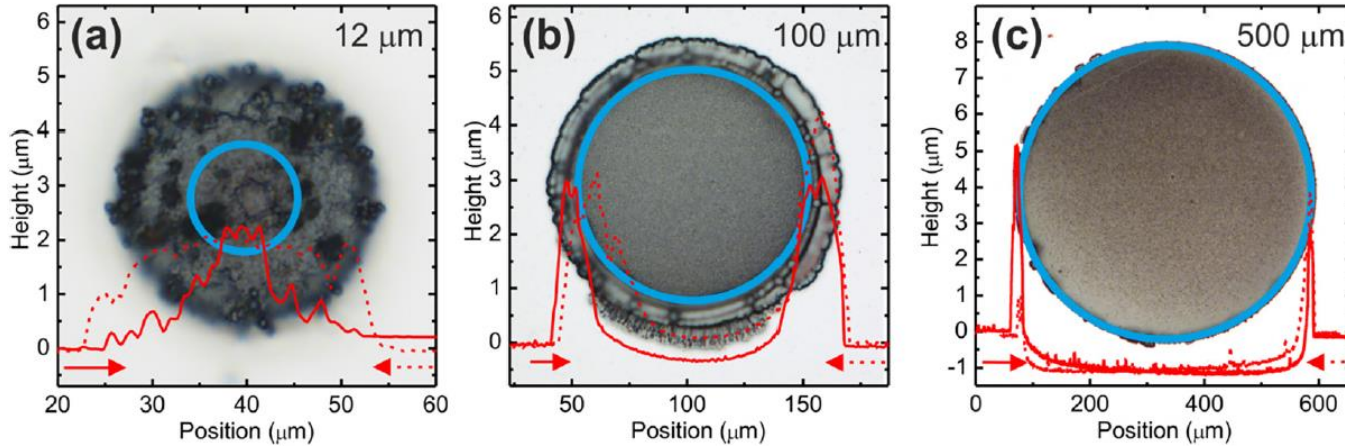
- CIGSe by electrodeposition on micro-electrodes



	J_{sc} (mA/cm ²)	V_{oc} (mV)	FF (%)	η (%)	Width (μ m)
0.1 cm ²	33.2	587	56.4	11.0	3160
1105 μ m	30.3	449	56.1	7.64	1105
105 μ m	30.2	368	48.3	5.38	105

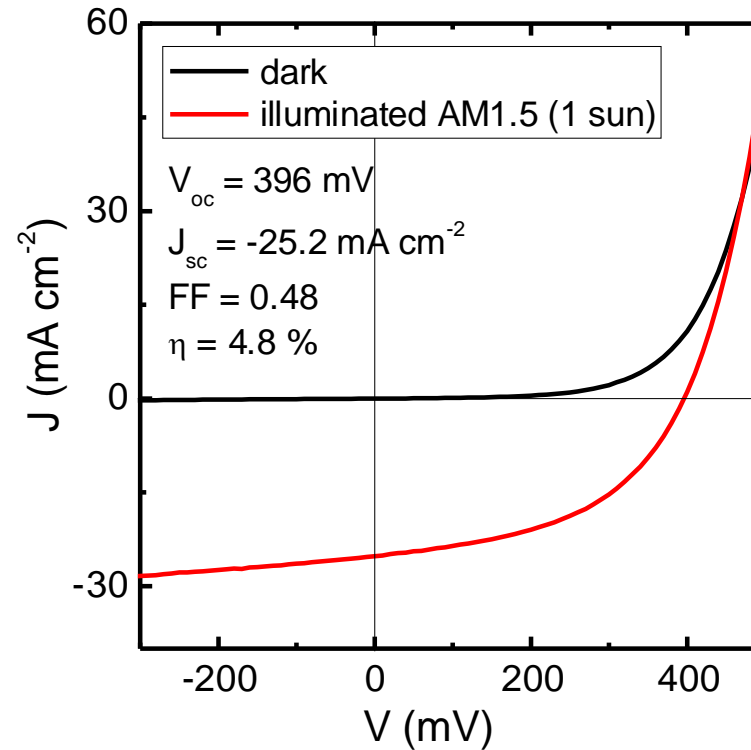
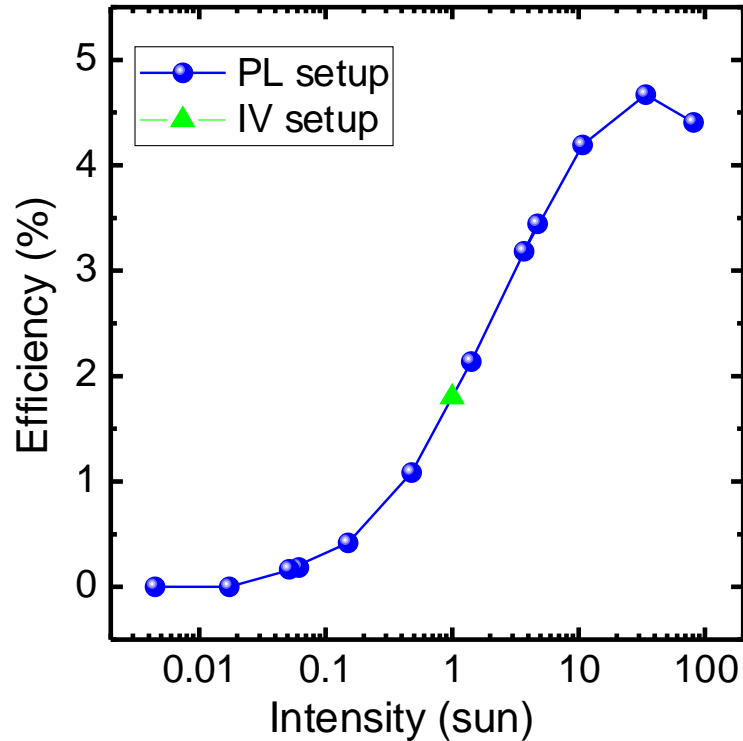
• $\eta = 5.38 \%$ for 105 μ m wide line-shaped cell under 1 sun illumination

- CIGSe by electrodeposition on micro-electrodes



- Electrodeposition on micro-electrodes is faster due to species arriving from non-depositing areas
- Balance of electrode size and diffusion length

- CIGSe by electrodeposition on micro-electrodes



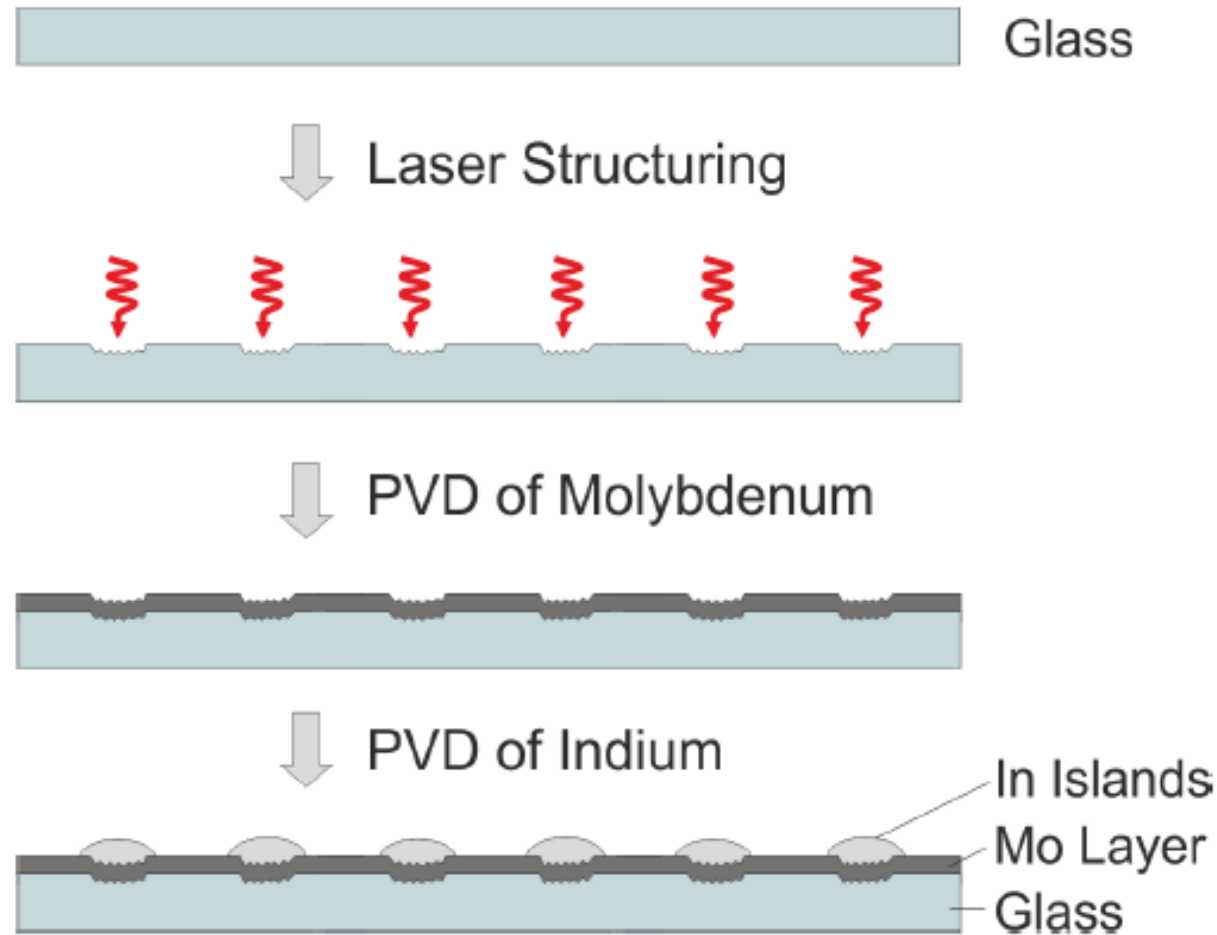
- $\eta = 4.8$ % @ 1 sun for 200 μ m micro solar cell
- $\eta = 4.6$ % @ 35X concentration for 200 μ m micro solar cell with 2 % @ 1 sun

D. Correia et al., Results in Physics 12, 2136 (2019).

D. Correia et al., Proc. IEEE PVSC, 794 (2018).

D. Siopa et al., submitted (2020).

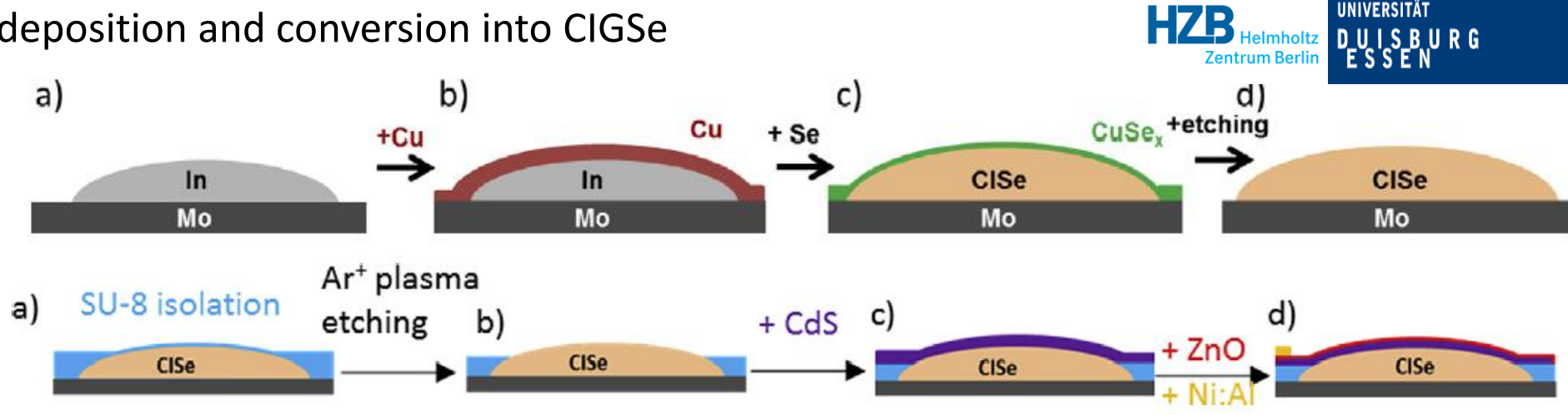
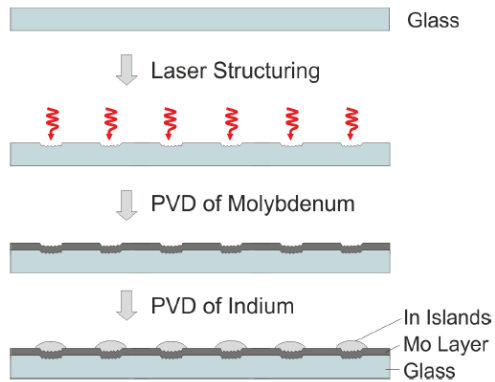
- Site-controlled indium deposition and conversion into CIGSe



B. Heidmann et al., Materials Today Energy 6, 238e247 (2017).

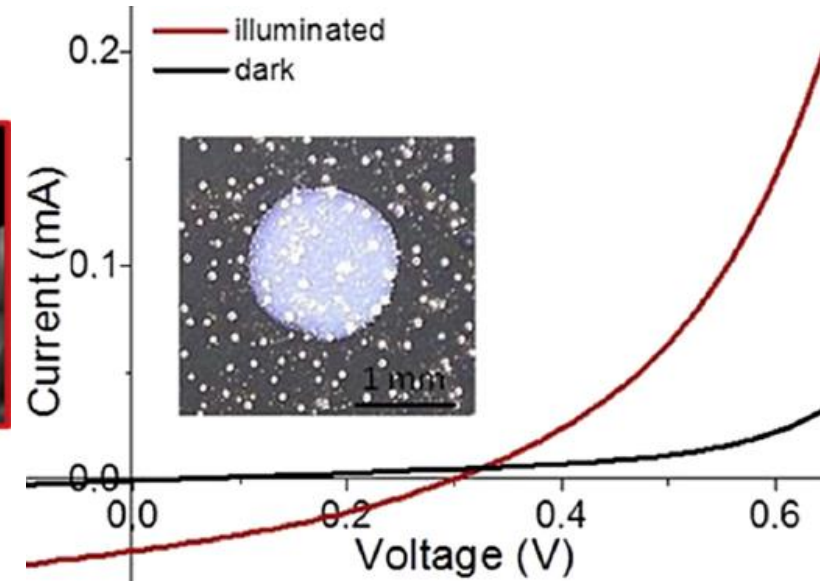
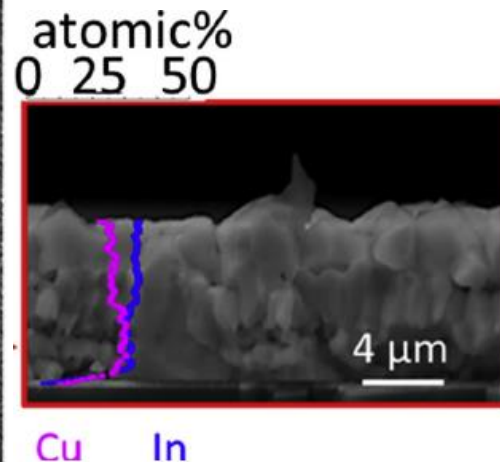
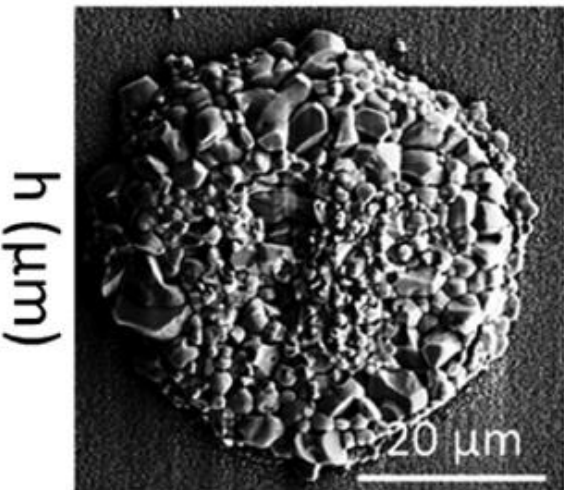
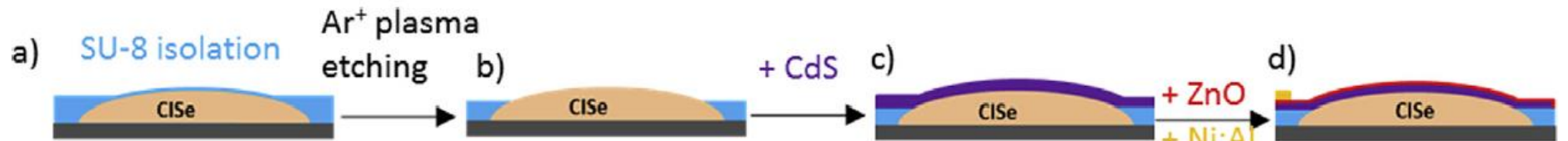
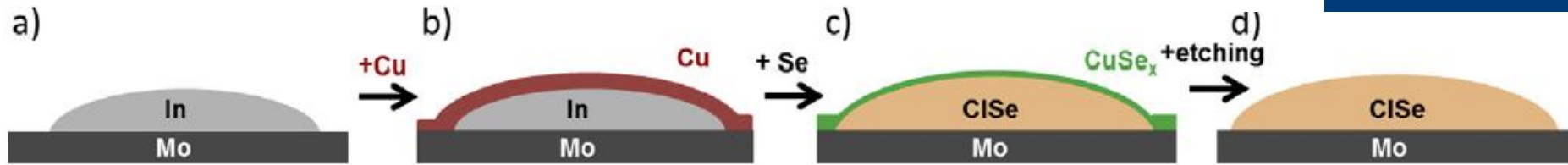
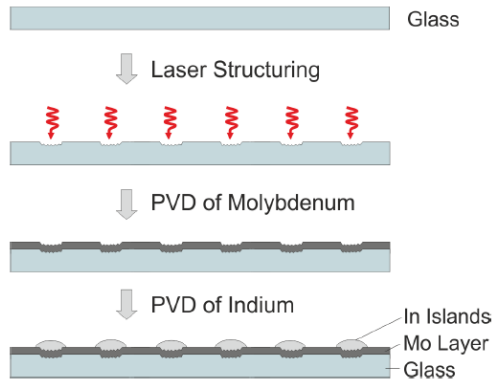
F. Ringleb et al., Beilstein J. Nanotechnol. 9, 3025 (2018).

- Site-controlled indium deposition and conversion into CIGSe



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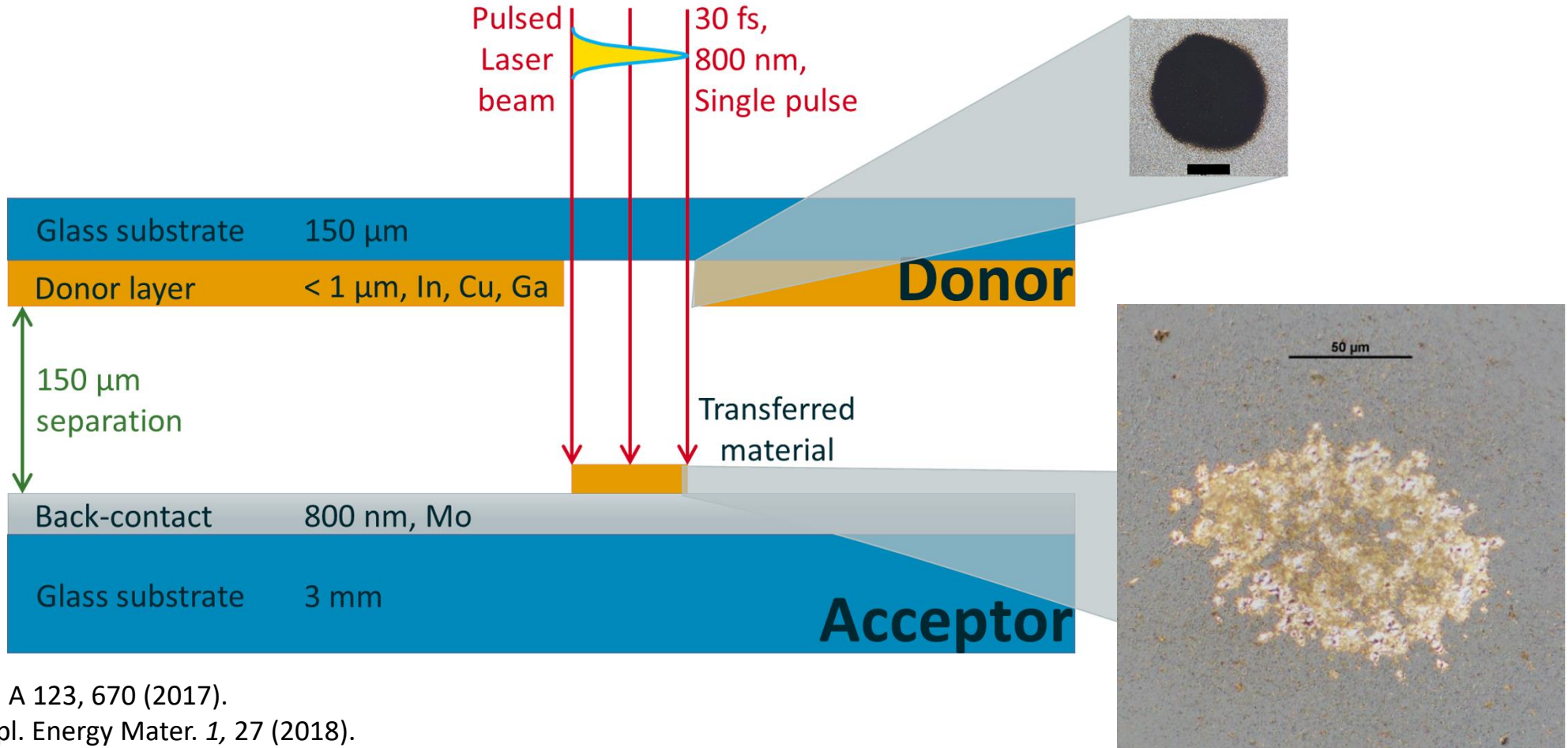
- Site-controlled indium deposition and conversion into CIGSe



- $\eta = 2.9 \% @ 1 \text{ sun}$ for 100 micro solar cells of $40 \mu\text{m}$
- $\eta = 3.1 \% @ 3X$ concentration

B. Heidmann et al., Materials Today Energy 6, 238e247 (2017).
F. Ringleb et al., Beilstein J. Nanotechnol. 9, 3025 (2018).

- Site-controlled indium deposition and conversion into CIGSe
 - LIFT – Laser-induced forward transfer

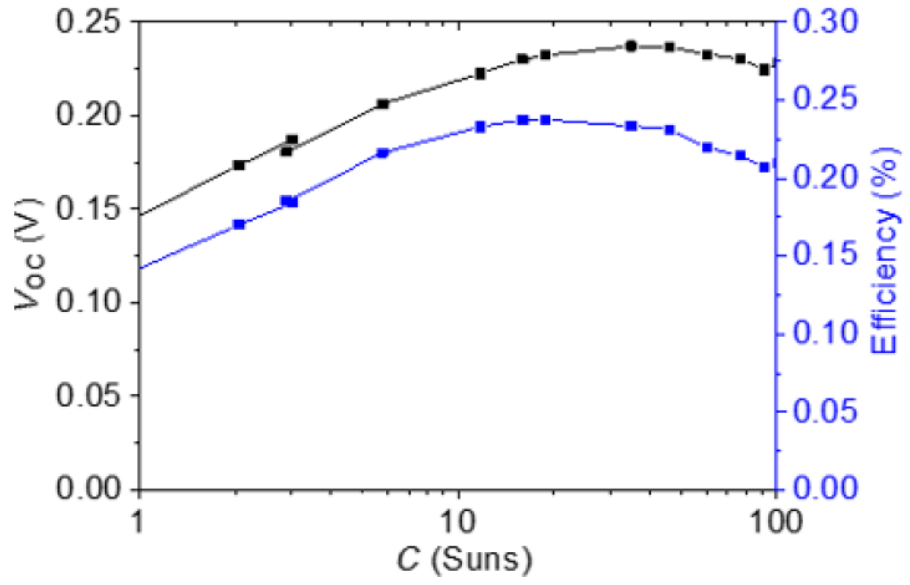
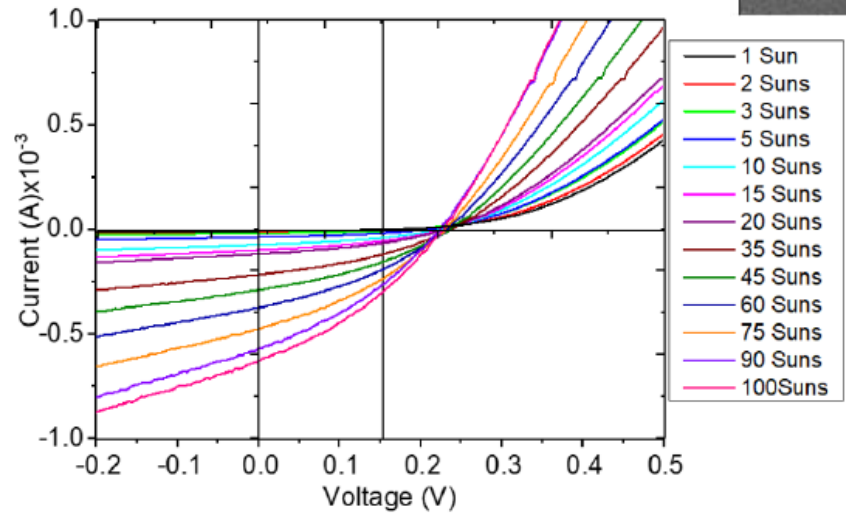
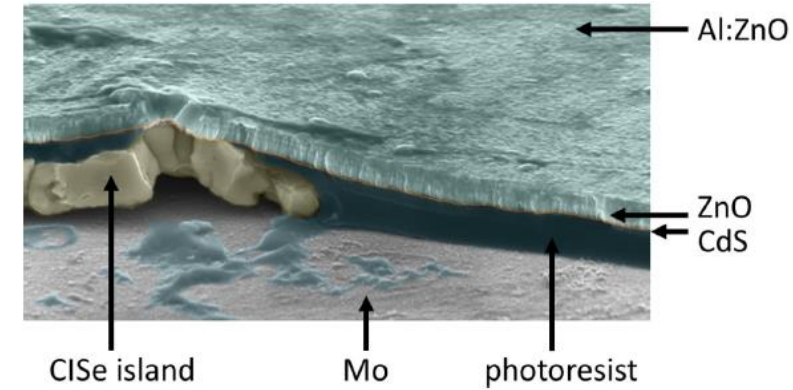
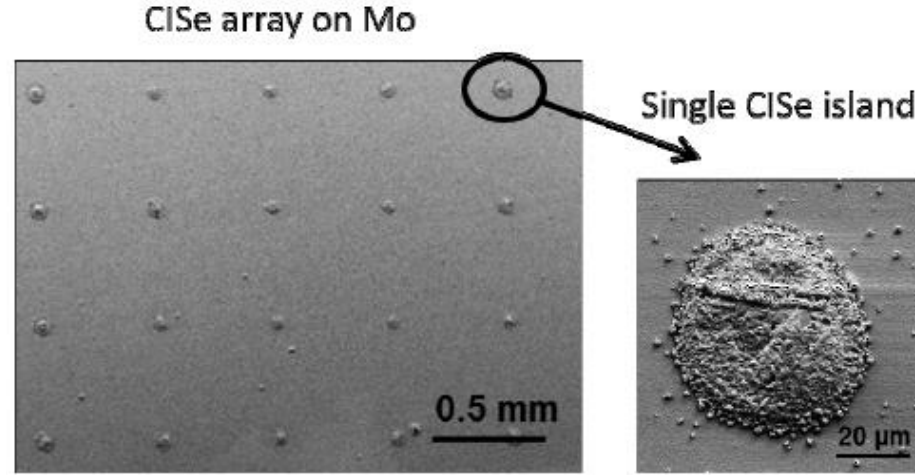
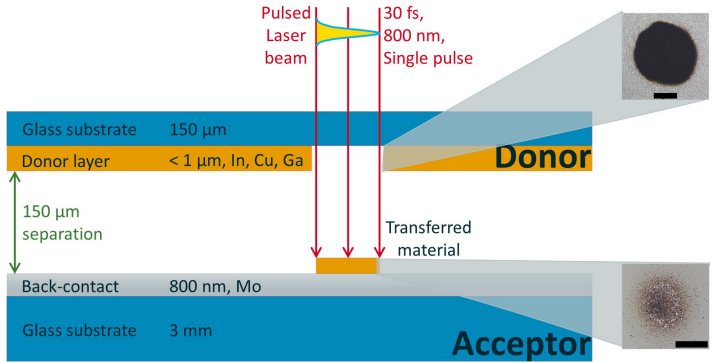


S. Andree et al., Appl. Phys. A 123, 670 (2017).

B. Heidmann et al., ACS Appl. Energy Mater. 1, 27 (2018).

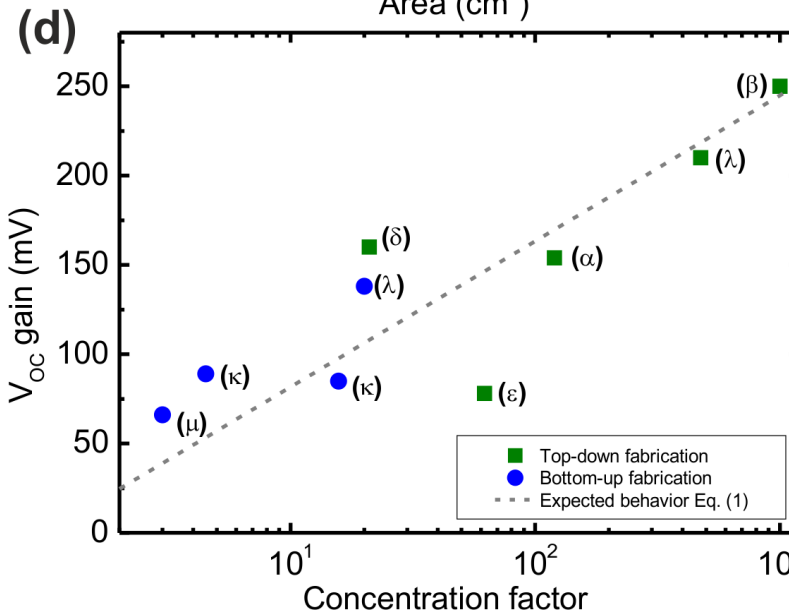
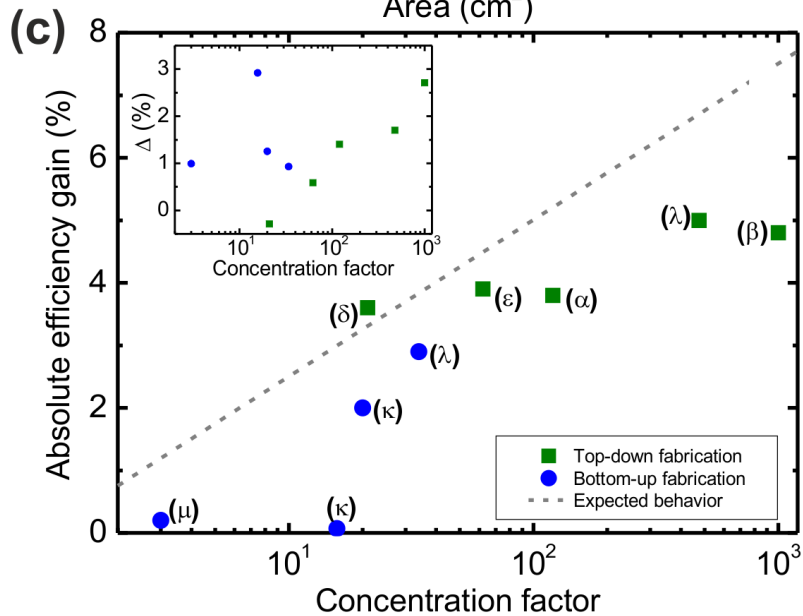
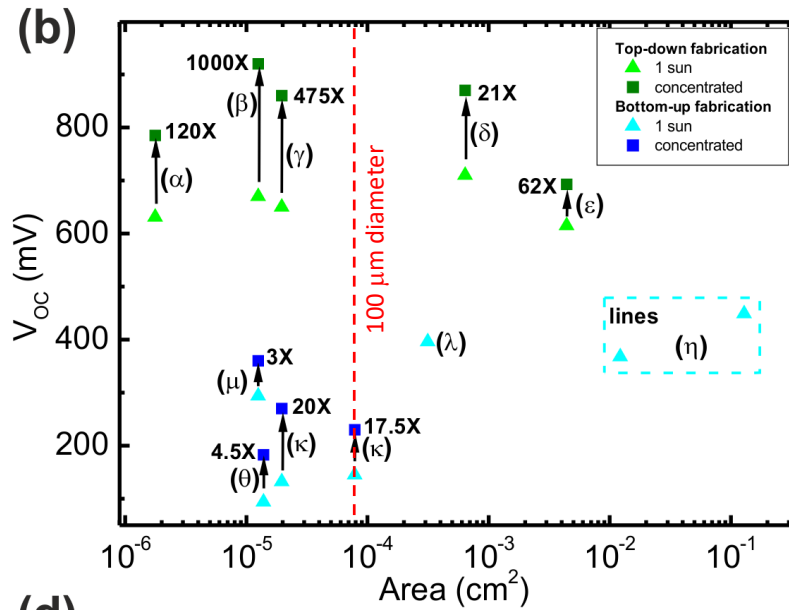
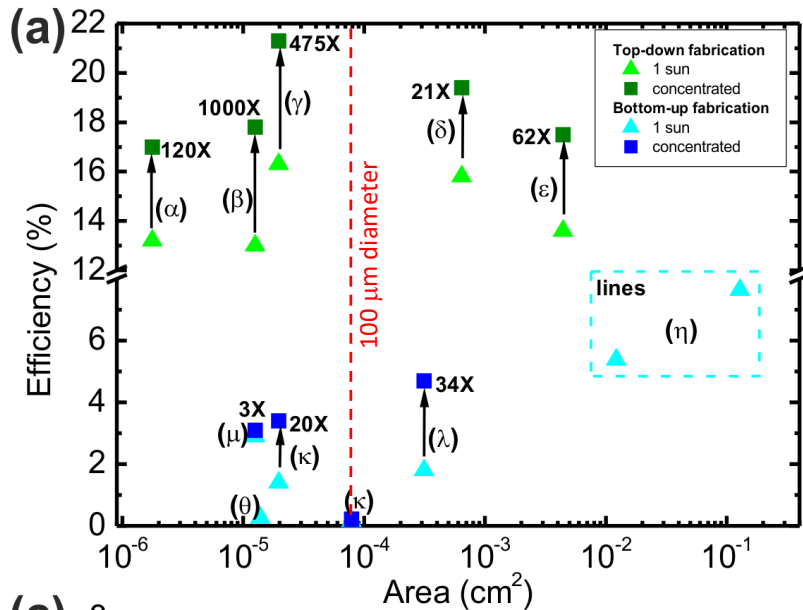
F. Ringleb et al., Beilstein J. Nanotechnol. 9, 3025 (2018).

- Site-controlled indium deposition and conversion into CIGSe



• $\eta = 0.24 \% @ 20 \text{ suns}$
for 25 micro solar cells
of 100 μm

S. Andree et al., Appl. Phys. A 123, 670 (2017).
B. Heidmann et al., ACS Appl. Energy Mater. 1, 27 (2018).
F. Ringleb et al., Beilstein J. Nanotechnol. 9, 3025 (2018).

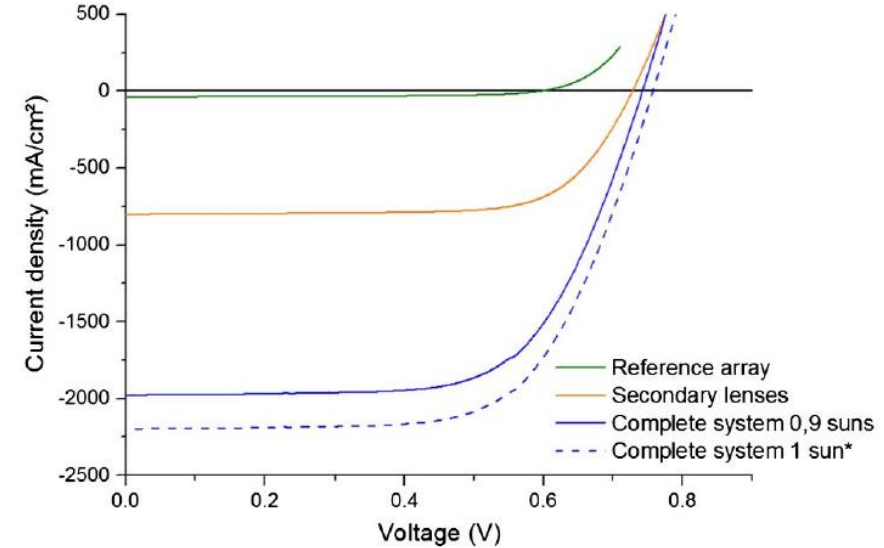
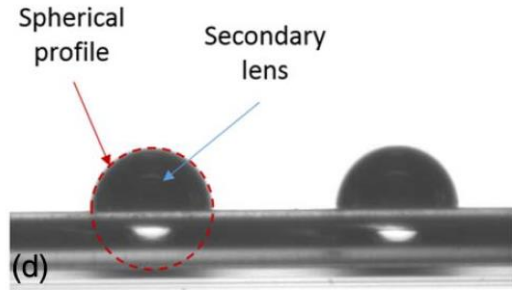
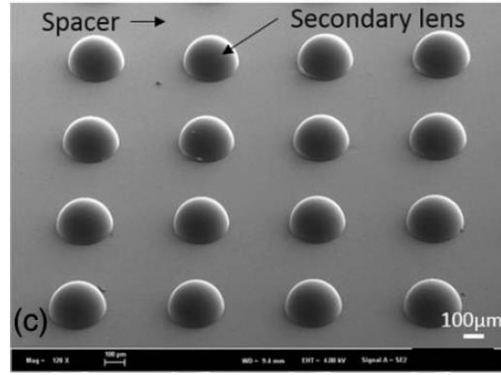
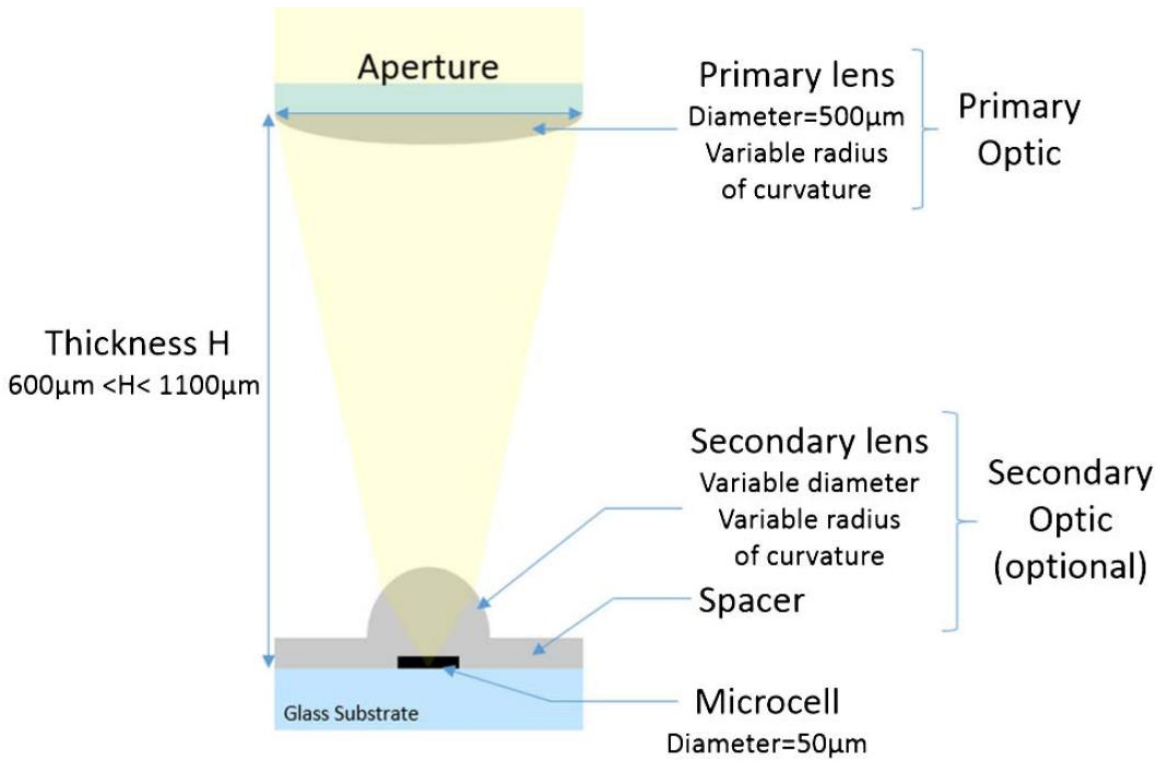


- Top-down fabrication leads to higher efficiencies and V_{oc}s
- Relative efficiency and V_{oc} gains are close to expected behavior
- Relative efficiency and Voc gains are similar for top-down and bottom-up approaches

M. Alves et al., J. Phys.: Energy 2, 012001 (2020).

Combination with Concentration Optics

Micro-concentrator thin-film photovoltaics



	Jsc (mA/cm ²)	Voc (V)	FF (%)	C Factor (exp.)	C Factor (th.)	Efficiency (%)
Reference array	30.6	594	59.6	1x	1x	10.8
Reference secondary lenses	799	727	71.9	26.1x	24.7x	13.5
Complete system (0.9 suns)	1978	742	65.5	64.6x	65.7x	12.4
Complete system (1 sun)*	2198	757	65.2	71.8x	73.1x	12.6

S. Juttau et al., Applied Optics 55, 6656 (2016).

- CIGSe micro-concentrator photovoltaics is a promising approach to reduce the requirement for critical raw materials
- Top-down fabrication of CIGSe micro solar cells has demonstrated up to 21.3 % efficiency at 475X concentration
- Various bottom-up fabrication routes have been demonstrated, currently still lower efficiencies
- Combination with micro optics has been demonstrated

“Thin-film micro-concentrator solar cells”

M. Alves, A. Pérez-Rodríguez, P.J. Dale, C. Domínguez, S. Sadewasser, J. Phys.: Energy 2, 012001 (2020).

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